

SE12DB, SE12DD, SE12DG, SE12DJ

Vishay General Semiconductor

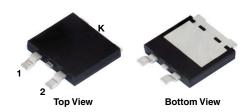
AUTOMOTIVE

COMPLIANT

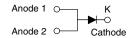
HALOGEN **FREE**

Surface-Mount ESD Capability Rectifiers

eSMP® Series SMPD (TO-263AC)



SE12DX



ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	12 A				
V _{RRM}	100 V, 200 V, 400 V, 600 V				
I _{FSM}	125 A				
V_F at $I_F = 12$ A ($T_A = 125$ °C)	0.96 V				
I _R	20 μΑ				
T _J max.	175 °C				
Package	SMPD (TO-263AC)				
Circuit configuration	Single				

FEATURES

- Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- · Oxide planar chip junction
- · Low forward voltage drop
- · ESD capability
- AEC-Q101 qualified
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

General purpose, power line polarity protection, in both consumer and automotive applications.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL SE12DB SE12DD SE12DG SE12DJ					UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	V _{RRM} 100 200 400 600			V	
Maximum DC forward current	I _F ⁽¹⁾	12				А
Maximum DC forward current	I _F (2)	3.2				
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	125			Α	
Operating junction and storage temperature range	T _J , T _{STG}	T _J , T _{STG} -55 to +175			°C	

Notes

(1) With heatsink

(2) Free air, mounted on recommended copper pad area

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage	I _F = 6 A	- T _A = 25 °C		0.95	-	V
	I _F = 12 A		V _E ⁽¹⁾	1.04	1.15	
	I _F = 6 A	- T _A = 125 °C	VF (')	0.85	-	
	I _F = 12 A			0.96	1.10	
Reverse current	Rated V _R	T _A = 25 °C T _A = 125 °C	I _R ⁽²⁾	-	20	μА
	nateu v _R		IR (=)	27	150	
Typical reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	3000	-	ns
Typical junction capacitance	4.0 V, 1 MHz		CJ	90	-	pF

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °c unless otherwise noted)						
PARAMETER	SYMBOL SE12DB SE12DG SE12DJ UNIT					
Typical thormal registance	R _{0JA} (1)(2)		°C/W			
Typical thermal resistance	R ₀ JC (3)	1.6				C/VV

Notes

- (1) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$
- $^{(2)}$ Free air, mounted on recommended PCB, 2 oz. pad area; thermal resistance $R_{\theta JA}$ junction to ambient
- (3) With infinite heatsink

IMMUNITY TO ELECTRICAL STATIC DISCHARGE TO THE FOLLOWING STANDARDS (T _A = 25 $^{\circ}$ C unless otherwise noted)						
STANDARD	TEST TYPE	TEST CONDITIONS	SYMBOL	CLASS	VALUE	
AEC-Q101-001	Human body model (contact mode)	C = 100 pF, R = 1.5 kΩ	V _C	НЗВ	> 8 kV	

ORDERING INFORMATION (Example)						
STANDARD	PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
SMPD (TO-263AC)	SE12DJ-M3/I	0.54	1	2000/reel	13" diameter plastic tape and reel	
SMPD (TO-263AC)	SE12DJHM3/I (1)	0.54	I	2000/reel	13" diameter plastic tape and reel	

Note

(1) AEC-Q101 qualified





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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

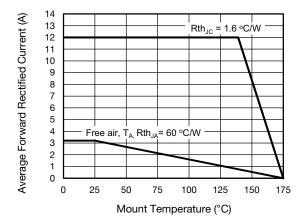


Fig. 1 - Forward Current Derating Curve

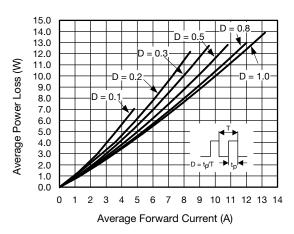


Fig. 2 - Forward Power Loss Characteristics

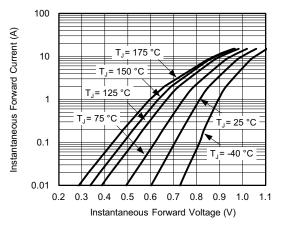


Fig. 3 - Typical Instantaneous Forward Characteristics

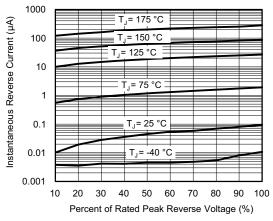


Fig. 4 - Typical Reverse Leakage Characteristics

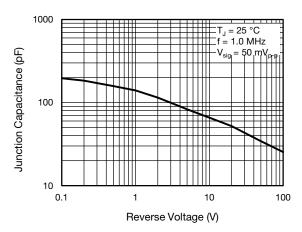


Fig. 5 - Typical Junction Capacitance

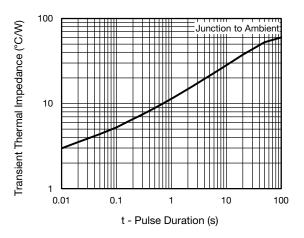


Fig. 6 - Typical Transient Thermal Impedance

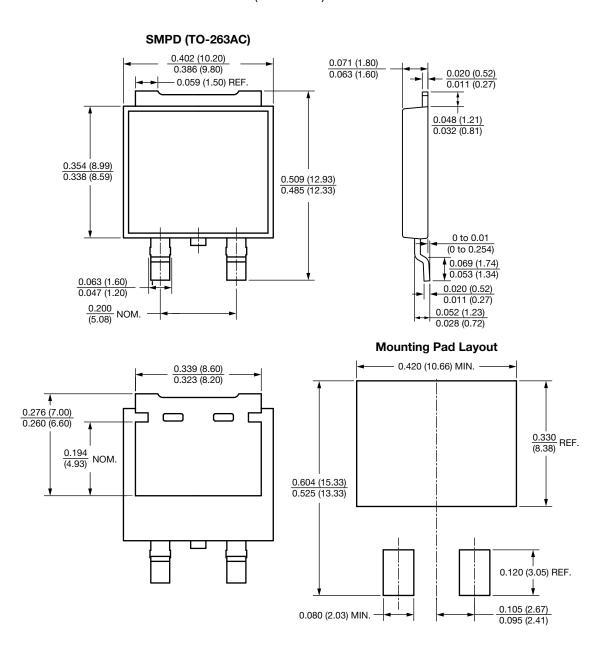




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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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